Application No.: 09/888,093 2 Docket No.: 249212013900

AMENDMENTS TO THE CLAIMS

This listing of claims will replace all prior versions, and listings, of claims in the application:

Claims 1-101 (canceled)

Claim 102 (currently amended): The An optical phase change tape, comprising, in this order: of claim 101,

a substrate comprising a polyaramid material;

a first heat absorbing layer comprising zinc sulfide and silicon oxide;

an optical recording layer comprising germanium, antimony, and tellurium; and

a second heat absorbing layer comprising zinc sulfide and silicon oxide,

wherein the optical recording layer is Ge₁Sb₁Te_{1.3}.

Claim 103 (currently amended): The optical phase change tape of claim 102 [[101]], wherein the optical recording layer is about 20 nanometers thick.

Claim 104 (currently amended): The optical phase change tape of claim 102 [[101]], wherein the substrate is about 4.4 microns thick.

Claim 105 (currently amended): The optical phase change tape of claim 102 [[101]], <u>further comprising a reflective layer disposed between the substrate and the first heat absorbing layer</u>, wherein the reflective layer is about 40 nanometers thick.

Claim 106 (currently amended): The optical phase change tape of claim 102 [[101]], wherein the first heat absorbing layer is about 20 nanometers thick.

Claim 107 (currently amended): The optical phase change tape of claim 102 [[101]], wherein the second heat absorbing layer is about 80 nanometers thick.

Claim 108 (currently amended): The optical phase change tape of claim 102 [[101]], wherein the magneto[[-]]optical recording layer is about 80 nanometers thick.

Claim 109 (currently amended): The optical phase change tape of claim 102 [[101]], wherein the substrate is about 5.2 microns thick.

Claim 110 (currently amended): The optical phase change tape of claim 102 [[101]], wherein the substrate comprises a polyethylene naphthalate material.

Claim 111 (currently amended): The An optical phase change tape, comprising, in this order: of claim 101,

a substrate comprising a polyaramid material; a first heat absorbing layer comprising zinc sulfide and silicon oxide; an optical recording layer comprising germanium, antimony, and tellurium; and a second heat absorbing layer comprising zinc sulfide and silicon oxide, wherein the optical recording layer is Ge₁Sb₁Te_{2,3}.

Claim 112 (currently amended): The optical phase change tape of claim 111 [[101]], wherein the optical recording layer is about 50 nanometers thick, layer of Ge₁Sb₁Te_{2.3}.

Claim 113 (currently amended): The optical phase change tape of claim 111 [[101]], <u>further</u> comprising a reflective layer disposed between the substrate and the first heat absorbing layer wherein the reflective layer comprises titanium.

Claim 114 (currently amended): The optical phase change tape of claim 113, wherein the reflective layer further comprises aluminum and titanium.

Claims 115-123 (canceled)